TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOS V)

TPC8118

Notebook PC Applications

- Small footprint due to small and thin package
- Low drain-source ON-resistance: R_{DS} (ON) = 5.5 m Ω (typ.)
- High forward transfer admittance: $|Y_{fs}| = 36 \text{ S} (typ.)$
- Low leakage current: $I_{DSS} = -10 \ \mu A \ (max) \ (V_{DS} = -30 \ V)$
- Enhancement mode: V_{th} = -0.8 to -2.0 V (V_{DS} = -10 V, I_D = -1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteri	stics	Symbol	Rating	Unit	
Drain-source voltage		V _{DSS}	-30	V	
Drain-gate voltage (R	_{GS} = 20 kΩ)	V _{DGR}	-30	V	
Gate-source voltage		V _{GSS}	±20	V	
Drain current	DC (Note 1)	۱ _D	-13	^	
Diamounent	Pulse (Note 1)	I _{DP}	-52	A	
Drain power dissipatio	n (t = 10 s) (Note 2a)	PD	1.9	W	
Drain power dissipatio	n (t = 10 s) (Note 2b)	PD	1.0	W	
Single pulse avalanch	e energy (Note 3)	E _{AS}	110	mJ	
Avalanche current		I _{AR}	-13	А	
Repetitive avalanche e (N	energy lote 2a) (Note 4)	E _{AR}	0.030	mJ	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Note 1, Note 2, Note 3 and Note 4: See the next page.

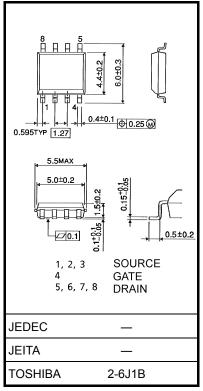
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating

temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

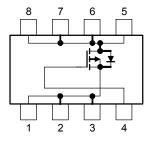
This transistor is an electrostatic-sensitive device. Handle with care.

Unit: mm



Weight: 0.080 g (typ.)

Circuit Configuration

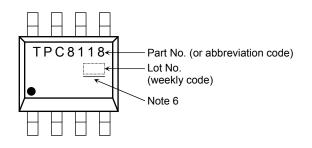


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Thermal Characteristics

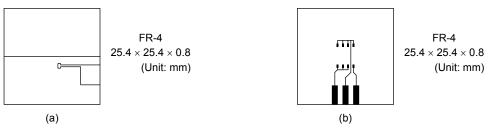
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R _{th (ch-a)}	65.8	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R _{th (ch-a)}	125	°C/W

Marking (Note 5)



Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)

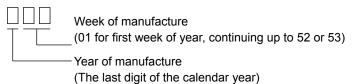


Note 3: $V_{DD} = -24 \text{ V}, \text{ T}_{ch} = 25^{\circ}\text{C}$ (initial), L = 500 μ H, R_G = 25 Ω , I_{AR} = -13 A

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: • on the lower left of the marking indicates Pin 1.

* Weekly code: (Three digits)



Note 6: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

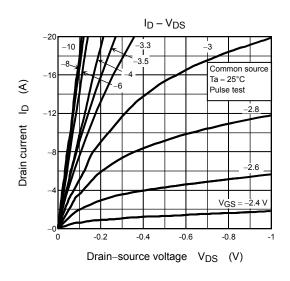
Electrical Characteristics (Ta = 25°C)

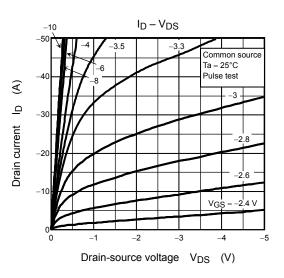
Char	racteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage curre	ent	I _{GSS}	$V_{GS}=\pm 20~V,~V_{DS}=0~V$	_		±100	nA
Drain cut-OFF cur	rent	I _{DSS}	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_		-10	μA
Drain-source brea	kdown voltage	V (BR) DSS	$I_D = -10$ mA, $V_{GS} = 0$ V	-30			V
Drain-source breakdown voltage		V (BR) DSX	$I_D = -10$ mA, $V_{GS} = 20$ V	-13	_	_	v
Gate threshold vol	tage	V _{th}	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -1 \text{ mA}$	-0.8	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		V
		R _{DS (ON)}	$V_{GS} = -4 \text{ V}, \text{ I}_D = -6.5 \text{ A}$	_	10	15	mΩ
Dialit-source ON-I	ain-source ON-resistance		$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -6.5 \text{ A}$	_	5.5	7.0	
Forward transfer admittance		Y _{fs}	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -6.5 \text{ A}$	18	36	_	S
Input capacitance	nput capacitance		V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	_	2700	_	pF
Reverse transfer capacitance		C _{rss}		_	600	_	
Reverse transfer capacitance Output capacitance		C _{oss}		_	860	_	
· · ·	Rise time	tr	$V_{CS} = 0 V \int I_D = -6.5 A$		9		
Switching time	Turn-on time	t _{on}	$V_{GS} \xrightarrow{0}_{-10} V \xrightarrow{I_D = -6.5 \text{ A}}_{OV} \xrightarrow{I_D = -6.5 \text{ A}}_{OV} \xrightarrow{OV}_{OUT}$	V 10 V -30 0V -13 nA -0.8 -2.0 A 10 15 5A 5.5 7.0 5A 18 36 V, f = 1 MHz 600 0 860 0 18 0 180 0 180 VDD \approx -15 V 460 655 655			
Switching time	Fall time	tf	$\begin{array}{c c} G & \clubsuit & & & \\ & & & & \\ & & & & \\ & & & &$		180	_	- ns
	Turn-off time	t _{off}		_	460	_	
Total gate charge (gate-source plus g	l gate charge e-source plus gate-drain) Qg		V _{DD} ≈ -24 V, V _{GS} = -10 V,		65		
Gate-source charge 1		Q _{gs1}	$I_{\rm D} = -13 \rm{A}$		10		nC
Gate-drain ("miller") charge		Q _{gd}			20		

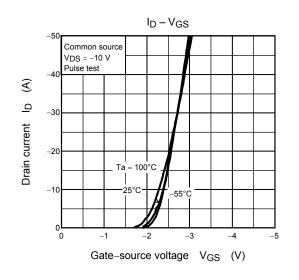
Source-Drain Ratings and Characteristics (Ta = 25°C)

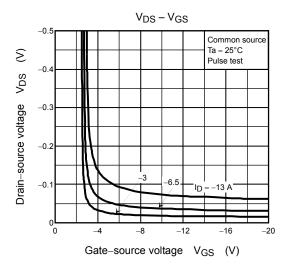
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Drain reverse current	Pulse	(Note 1)	I _{DRP}	—	_	_	-52	А
Forward voltage (diode)		V _{DSF}	$I_{DR} = -13 \text{ A}, \text{ V}_{GS} = 0 \text{ V}$		_	1.2	V	

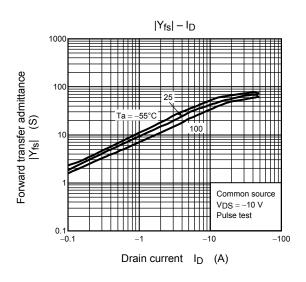
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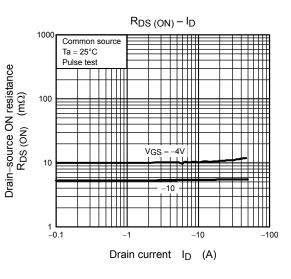




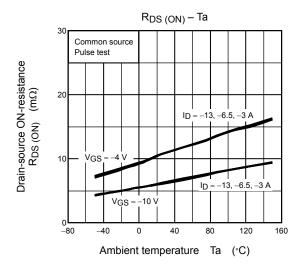


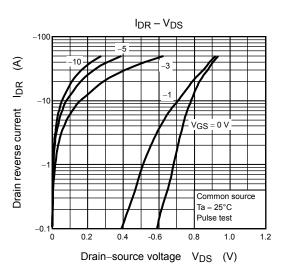


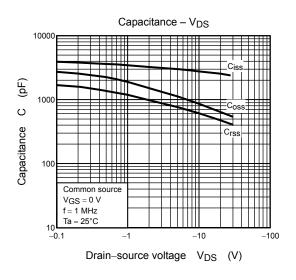


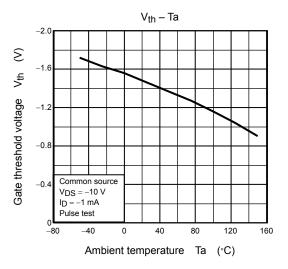


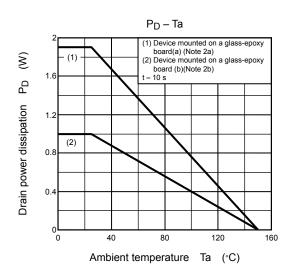
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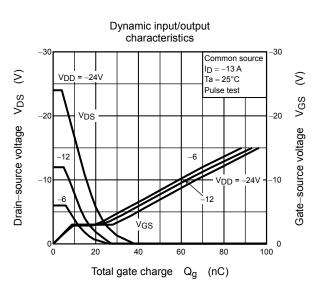


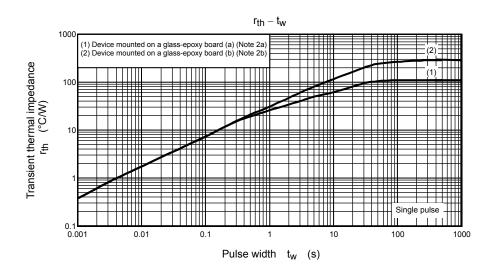


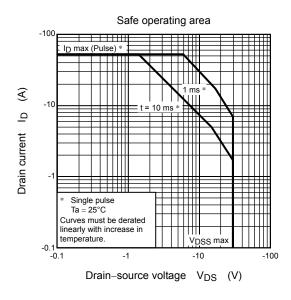












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